# **Preliminary**

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

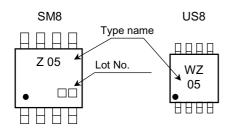
# TC7WZ05FU, TC7WZ05FK

Triple Inverter (open drain)

#### **Features**

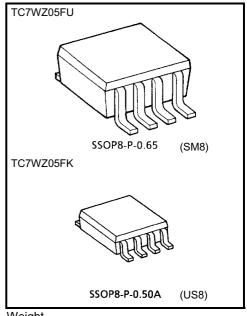
- High output drive: 24 mA (min) @VCC = 3 V
- Super high speed operation: tpZL 2.3 ns (typ.) @VCC = 5 V, 50 pF
- Operation voltage range:  $V_{CC (opr)} = 1.65 \sim 5.5 \text{ V}$
- Latch-up performance: ±500 mA or more
- ESD performance: ±200 V or more (EIAJ) ±2000 V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

#### Marking



### Maximum Ratings (Ta = 25°C)

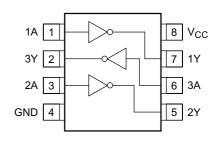
Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	-0.5~6	V	
DC input voltage	V <sub>IN</sub>	-0.5~6	V	
DC output voltage	V <sub>OUT</sub>	-0.5~6	V	
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	lok	-20	mA	
DC output current	lout	50	mA	
DC V <sub>CC</sub> /ground current	Icc	±50	mA	
Power dissipation	P <sub>D</sub>	300 (SM8) 200 (US8)	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	
Lead temperature (10s)	TL	260	°C	



Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

#### Pin Assignment (top view)



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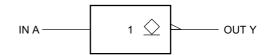


#### **Truth Table**

А	Υ
L	*H
Н	L

#### \*: High impedance

#### **Logic Diagram**



#### **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	1.65~5.5	V	
Supply voltage	VCC	1.5~5.5 (Note 1)	Ī	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V	
		0~V <sub>CC</sub> (Note 3)		
Operating temperature	T <sub>opr</sub>	-40~85	°C	
		$0~20~(V_{CC} = 1.8~V \pm 0.15~V, \\ 2.5~V \pm 0.2~V)$	ns/V	
Input rise and fall time	d <sub>t</sub> /d <sub>v</sub>	0~10 (V <sub>CC</sub> = 3.3 V ± 0.3 V)		
		$0~5~(V_{CC} = 5.5~V \pm 0.5~V)$		

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ Note 3: Low state

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#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics		Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit	
Charac	Onaractoristics Symbol Fest Collution		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic		
High level	High lovel	VIH	_		1.65~ 1.95	0.75 × V <sub>CC</sub>	_	_	0.75 × V <sub>CC</sub>		V
	T light level				2.3~5.5	0.7 ×V <sub>CC</sub>	_	_	0.7 × V <sub>CC</sub>		
voltage	I ow level	ow level V <sub>IL</sub>	_		1.65~ 1.95		_	0.25 ×V <sub>CC</sub>	_	0.25 × V <sub>CC</sub>	
Low le	Low level				2.3~5.5		_	0.3 ×V <sub>CC</sub>		$0.3 \\ \times V_{CC}$	
		VoL	V <sub>IN</sub> = V <sub>IH</sub>	Ι <sub>ΟL</sub> = 100 μΑ	1.65	_	0	0.1	—	0.1	
					2.3	_	0	0.1	—	0.1	V
					3.0	_	0	0.1		0.1	
					4.5	_	0	0.1	_	0.1	
Output voltage	Low level			I <sub>OL</sub> = 4 mA	1.65	_	0.08	0.24	_	0.24	
				I <sub>OL</sub> = 8 mA	2.3	_	0.1	0.3		0.3	
				I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4		0.4	
				I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55		0.55	
				I <sub>OL</sub> = 32 mA	4.5	_	0.22	0.55	_	0.55	
Input leakage	current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0~5.5	_		±1		±10	μΑ
Off-state carrent		loz	$V_{IN} = V_{IL},$ $V_{OUT} = V_{CC}$ or GND		5.5	_	_	±5	_	±10	μΑ
Power off lea	kage current	loff	V <sub>IN</sub> or V <sub>OL</sub>	<sub>JT</sub> = 5.5 V	0.0	_	_	1	_	10	μΑ
Quiescent supply current		Icc	V <sub>IN</sub> = 5.5 V or GND		1.65~5.5	_	_	1	_	10	μΑ



#### AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol	rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
Propagation delay time	<sup>t</sup> pZL	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$1.8 \pm 0.15$	1.8	5.5	9.5	1.8	10.5	
			$2.5\pm0.2$	1.2	3.7	5.8	1.2	6.4	- ns
			$3.3 \pm 0.3$	0.8	2.9	4.4	0.8	4.8	
			$5.0 \pm 0.5$	0.5	2.3	3.5	0.5	3.9	
	t <sub>pLZ</sub>	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$1.8 \pm 0.15$	1.8	4.3	9.5	1.8	10.5	
			2.5 ± 0.2	1.2	2.8	5.8	1.2	6.4	
			$3.3 \pm 0.3$	0.8	2.1	4.4	8.0	4.8	
			$5.0 \pm 0.5$	0.5	1.4	3.5	0.5	3.9	
Input capacitance	C <sub>IN</sub>	_	0~5.5	_	3.0	_	_	_	pF
Output capacitance	C <sub>OUT</sub>	_	0~5.5	_	3.0	_	_	_	pF
Power dissipation capacitance	0	(Note)	3.3	_	5.2	_	_		pF
	C <sub>PD</sub> (Not		5.5	_	8.5	_	_	_	pΓ

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

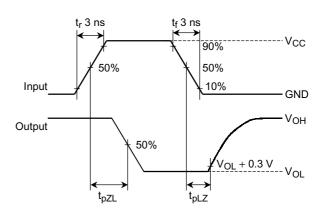
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$ 

#### **Test Circuit**

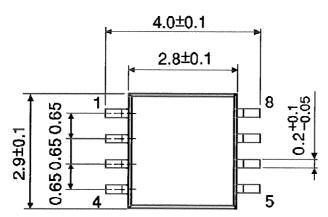
# Output $\circ$ $R_L \nearrow$ $R_L \nearrow$

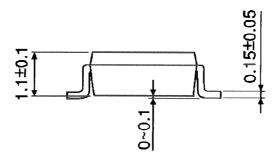
#### **AC Waveform**



# **Package Dimensions**

SSOP8-P-0.65 Unit: mm



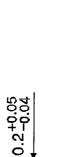


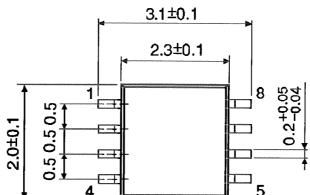
Weight: 0.02 g (typ.)

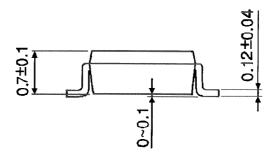
Unit: mm

# **Package Dimensions**

SSOP8-P-0.50A







Weight: 0.01 g (typ.)